Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	340	shot and exposure adj apparatus and memory and (compare or comparing or comparision)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 12:47
S2	248	control and data and semiconductor and S1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/02 14:01
S3	575	shot adj data	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/02 14:01
S4	26	exposure adj apparatus and memory and S3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/02 14:02
S5	4	("5329130").URPN.	USPAT	OR	ON	2005/06/28 09:04
S6	1354	yamada.in. and electron adj beam	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 08:44
S7	558	control and S6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 08:44
S8	12190	first adj buffer and second buffer and S7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 09:04
S9	1	first adj buffer and second adj buffer and S7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 08:45

S10	771	first adj buffer adj memory and second adj buffer and memory	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 08:46
S11	18	electron adj beam and S10	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 10:51
S12	17147	fujitsu.as.	USPAT	OR	ON	2005/06/28 09:04
S13	16167	first adj buffer and second buffer and S12	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 10:45
S14	995	wafer and S13	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 09:05
S15	271	(compare or comparing or comparision) and S14	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 09:06
S16	3	second adj exposure and S15	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 09:06
S17	4	("5329130").URPN.	USPAT	OR	ON	2005/06/28 10:21
S18	2	("5895924").URPN.	USPAT	OR	ON	2005/06/28 10:24
S19	7	("5359202" | "5712488" | "5798196" | "5834783" | "5895924" | "5929457" | "5973332").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/28 10:26
S20	9228	first adj buffer and second adj buffer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 10:46

S21	1390	electron adj beam adj exposure adj apparatus	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 10:52
S22	2	S20 and S21	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 10:52
S23	2	("5798196").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/28 11:40
S24	301	cpu same second adj buffer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 11:44
S25	2	electron adj beam and S24	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/28 11:44
S26	4	("5329130").URPN.	USPAT	OR	ON	2005/12/15 12:06
S27	740035	electron beam adj exposure	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 12:06
S28	1025	second adj buffer adj memory	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 12:07
S29	34	S27 and S28	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 12:07

S30	31727	"no error"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 12:07
S31	0	S29 and S30	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 12:07
S32	390	(438/5).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/15 13:18
S33	963	(250/505.1).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/15 14:04
S34	1	(second adj buffer adj memory and electron adj beam and (wafer or substrate) and error).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 14:05